

## Features

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications



SOD-123FL

## Mechanical Data

- Case: SOD-123FL
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 15mg 0.00048oz

## Pinning

PIN	DESCRIPTION
1	Cathode
2	Anode

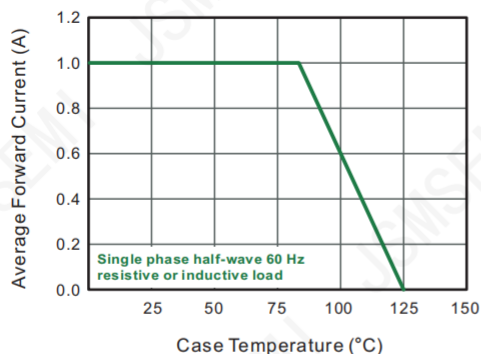
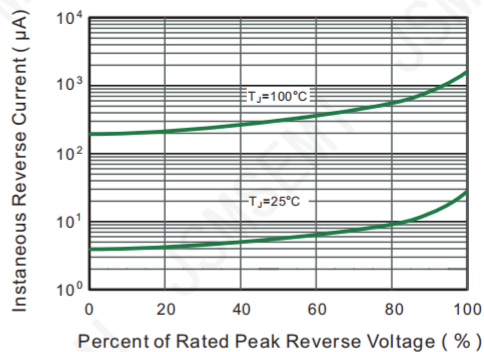
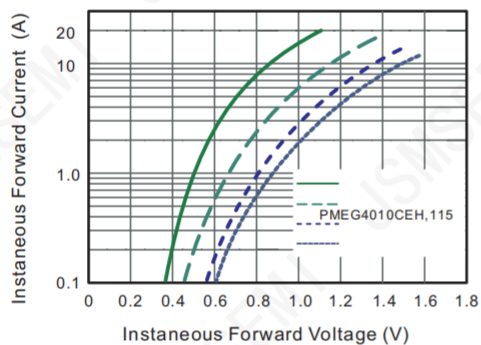
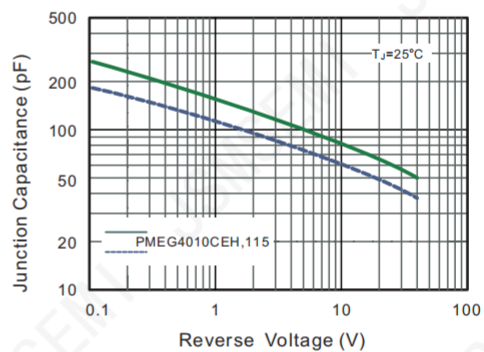
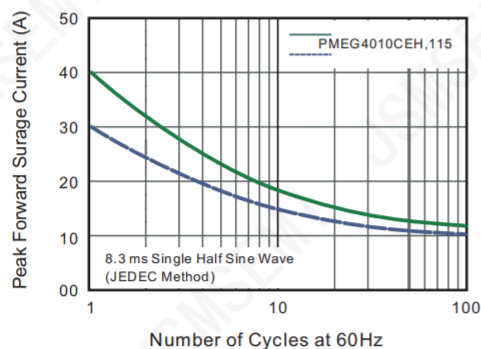
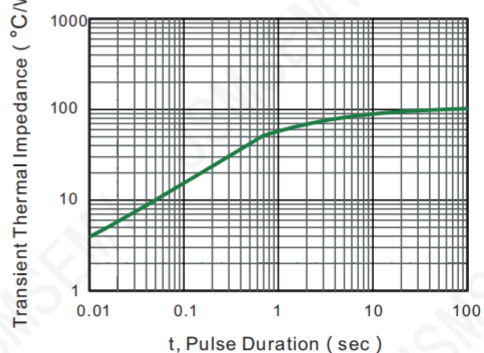
## Absolute Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

Parameter	Symbols	PMEG4010CEH,115-JSM	Units
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	40	V
Maximum RMS voltage	$V_{RMS}$	28	V
Maximum DC Blocking Voltage	$V_{DC}$	40	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	1.0	A
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	$I_{FSM}$	30	A
Max Instantaneous Forward Voltage at 1 A	$V_F$	0.55	V
Maximum DC Reverse Current at Rated DC Reverse Voltage $T_a = 25^{\circ}C$ $T_a = 100^{\circ}C$	$I_R$	0.3 10	mA
Typical Junction Capacitance <sup>(1)</sup>	$C_j$	110	pF
Typical Thermal Resistance <sup>(2)</sup>	$R_{\theta JA}$	100	$^{\circ}C/W$
Operating Junction Temperature Range	$T_j$	-55 ~ +125	$^{\circ}C$
Storage Temperature Range	$T_{stg}$	-55 ~ +150	$^{\circ}C$

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

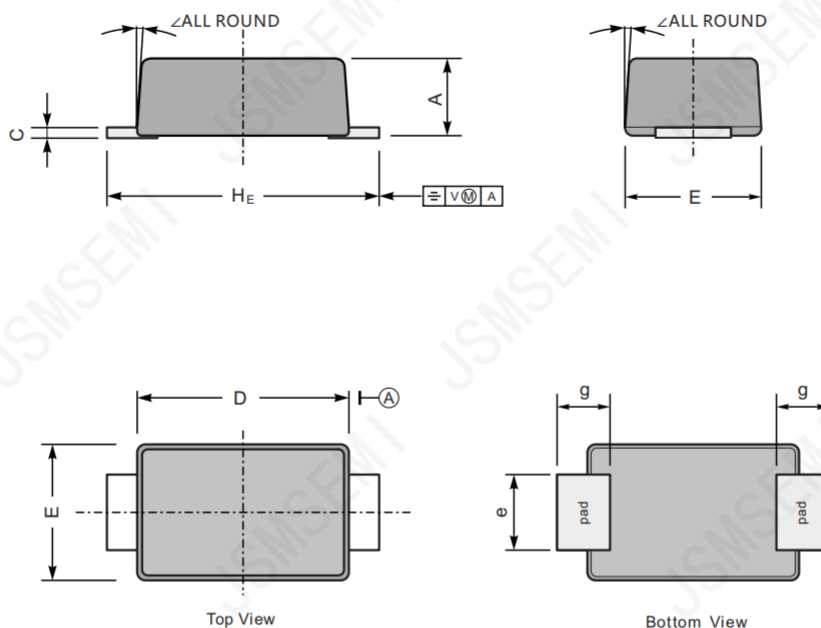
(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

**Fig.1 Forward Current Derating Curve**

**Fig.2 Typical Reverse Characteristics**

**Fig.3 Typical Forward Characteristic**

**Fig.4 Typical Junction Capacitance**

**Fig.5 Maximum Non-Repetitive Peak Forward Surge Current**

**Fig.6- Typical Transient Thermal Impedance**


## Package Outline

Plastic surface mounted package; 2 leads

SOD-123FL



UNIT		A	C	D	E	e	g	H <sub>E</sub>	7°
mm	max	1.1	0.20	2.9	1.9	1.1	0.9	3.8	
	min	0.9	0.12	2.6	1.7	0.8	0.7	3.5	
mil	max	43	7.9	114	75	43	35	150	
	min	35	4.7	102	67	31	28	138	

## Revision History

Rev.	Change	Date
V1.0	Initial version	6/27/2021

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